DECLARATION FOR PATENT APPLICATION & POWER OF ATTORNEY

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name,

below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled:

ELECTRICALLY-CONDUCTIVE GRID SHIELD FOR SEMICONDUCTORS

X is attached was filed of	on	cone) as Application Serial No (if applicable)		
	cification, including	reviewed and understand the the claims, as amended by a		
	•	o disclose all information know e 37, Code of Federal Regulat		
§ 119 of any thave also ide	foreign application(ntified below any fo	ority benefits under Title 35, Units) for patent or inventor's certionerign application for patent or of the application on which prio	ficate listed below and inventor's certificate	
PRIOR FOREIGN APPLICATION(S)			Priority claimed	
(Number)	(Country)	(Day/month/year filed)	Yes No	_
(Number)	(Country)	(Day/month/year filed)	Yes No	_
(Number)	(Country)	(Day/month/year filed)	Yes No	
I hereby o	laim the benefits u	nder Title 35, United States Co	ode, § 120 of any	

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United States application(s) listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of Title 35, United States Code, § 112, I acknowledge the duty to disclose material information as defined in Title 37, Code of Federal Regulations, § 1.56(a) which occurred between the filing date of the prior application and the national or PCT international filing date of this application:

(Application Serial No.)	(Filing date)	(Status) (patented,pending,abandoned)	
(Application Serial No.)	(Filing date)	(Status) (patented,pending,abandoned)	

<u>Power of Attorney</u>: As a named inventor, I hereby appoint the following attorney(s) and/or agent(s) to prosecute this application and transact all business in the Patent and Trademark Office connected therewith.

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I hereby declare that all statements made herein on my own knowledge are true and that all statements made on information and belief are believed to be true, and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false

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statements may jeopardize the validity of the application or any patent issuing thereon.

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: David Whitney et al. Art Unit: 2831
Serial No.: 09/547,475
Examiner: H. Ngo

Filed : April 12, 2000

Title : ELECTRICALLY-CONDUCTIVE GRID SHIELD FOR SEMICONDUCTORS

Commissioner for Patents Washington, D.C. 20231

ASSOCIATE POWER OF ATTORNEY

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Please continue to direct all official communications to the undersigned.

Respectfully submitted,

Date: 1/4/02 Heather S. Vance, Reg. No. 39,033
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CERTIFICATE OF MAILING BY FIRST CLASS MAIL

I hereby certify under 37 CFR §1.8(a) that this correspondence is being deposited with the United States Postal Service as first class mail with sufficient postage on the date indicated below and is addressed to the Commissioner for Patents, Washington, D.C. 20231.

Date of Deposit

Maye Sawardzyc

Signature

Maya Samardzija
Typed or Printed Name of Person Signing Certificate